

## Special Issue

# Advances in GaN-Based Electronic Materials and Devices

### Message from the Guest Editor

Thick epitaxial GaN power switching devices are known to contain a high density of crystal defects, especially threading dislocations in the epitaxial layer. The impact of these defects on device performance, manufacturing yield, and long-term field-reliability, especially when operating under extremely stressful high voltage environments, is a topic of ongoing research. This Special Issue encourages manuscripts on defects in thick GaN epi and their impact on the power electronic switch, as well as the latest results on unique substrates for GaN device quality epitaxial layer growth. This Special Issue also encourages manuscripts to be submitted addressing all reliability issues, especially those related to failure mechanisms. Innovative research results of special GaN-based devices and circuits are also encouraged to be submitted to this Special Issue for publication. I look forward to receiving your contributions.

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### Guest Editor

Prof. Dr. Aristotelis Christou

Materials Science Department, University of Maryland, College Park, MD 20745, USA

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### Deadline for manuscript submissions

15 April 2025



## Electronics

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*Electronics*  
MDPI, Grosspeteranlage 5  
4052 Basel, Switzerland  
Tel: +41 61 683 77 34  
[electronics@mdpi.com](mailto:electronics@mdpi.com)

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## About the Journal

### Message from the Editor-in-Chief

*Electronics* is a multidisciplinary journal designed to appeal to a diverse audience of research scientists, practitioners, and developers in academia and industry. The journal is devoted to fast publication of latest technological breakthroughs, cutting-edge developments, and timely reviews of current and emerging technologies related to the broad field of electronics. Experimental and theoretical results are published as regular peer-reviewed articles or as articles within Special Issues guest-edited by leading experts in selected topics of interest.

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### Editor-in-Chief

Prof. Dr. Flavio Canavero

Department of Electronics and Telecommunications, Politecnico di Torino, 10129 Torino, Italy

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